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<u>Vishay Semiconductor/Diodes Division</u> <u>VS-60CPU02-N3</u>

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VS-60CPU02-N3 - DIODE ARRAY GP 200V 30A TO247AC

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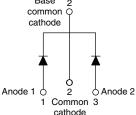
Vishay Semiconductors

VS-60CPU02-F, VS-60CPU02-N3

Ultrafast Rectifier, FRED Pt®, 2 x 30 A

Base 2 common O





PRODUCT SUMMARY					
Package	TO-247AC				
I _{F(AV)}	2 x 30 A				
V _R	200 V				
V _F at I _F	0.75 V				
t _{rr} typ.	30 ns				
T _J max.	175 °C				
Diode variation	Common cathode				

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS
COMPLIANT
HALOGEN
FREE

DESCRIPTION / APPLICATIONS

VS-60CPU02... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, welding, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Repetitive peak reverse voltage		V_{RRM}		200	V	
Average rectified forward current	per leg			30		
per	device	I _{F(AV)}	Rated V _R , T _C = 145 °C	60	۸	
Non-repetitive peak surge current per leg		I _{FSM}	T _J = 25 °C	300	А	
Peak repetitive forward current per leg		I _{FM}	Rated V_R , square wave, 20 kHz, T_C = 137 °C	60		
Operating junction and storage temperature	es	T _J , T _{Stg}		-65 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	Ι _R = 100 μΑ	200	-	-		
Forward voltage	V _F	I _F = 30 A	-	0.92	1.1	V	
		I _F = 30 A, T _J = 150 °C	-	0.75	0.85		
Daviera la dia na avimant		$V_R = V_R$ rated	-	-	50		
Reverse leakage current	I _R	T _J = 150 °C, V _R = V _R rated	-	30	300	μΑ	
Junction capacitance C _T V		V _R = 200 V	-	100	-	pF	
Series inductance L _S Measured lead to lead 5 mm from package body		1	12	-	nH		

Revision: 10-Jul-15 1 Document Number: 94657

Datasheet of VS-60CPU02-N3 - DIODE ARRAY GP 200V 30A TO247AC

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	AMETER SYMBOL TEST CONDITIONS					MAX.	UNITS	
		I _F = 1.0 A, dI _F /dt =	100 A/μs, V _R = 30 V	-	30	36		
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 30 A dI _F /dt = - 200 A/μs V _R = 160 V	-	30	-	ns	
		T _J = 125 °C		-	47	-		
Peak recovery current	I _{RRM}	T _J = 25 °C		-	3	-	A nC	
		T _J = 125 °C		-	6.5	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	42	-		
		T _J = 125 °C		-	160	-		

THERMAL - MECHANICAL SPECIFICATIONS (T _J = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance, junction to case per leg	R _{thJC}		-	0.6	1.0		
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	40	°C/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
Majaht			-	6.0	-	g	
Weight			-	0.21	-	OZ.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-247AC	60CPU02				

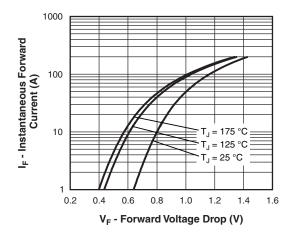


Fig. 1 - Typical Forward Voltage Drop Characteristics

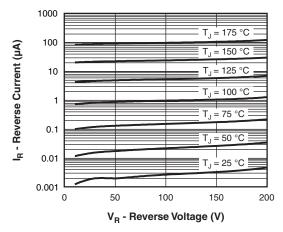


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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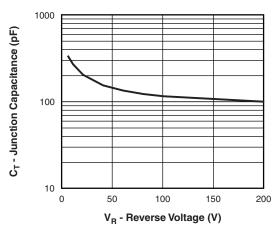


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

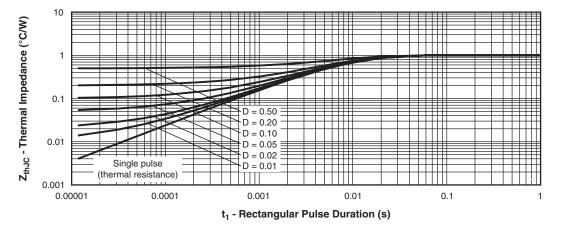


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

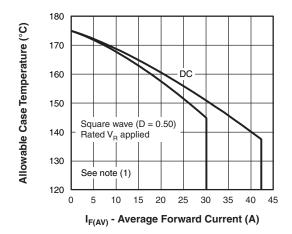


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

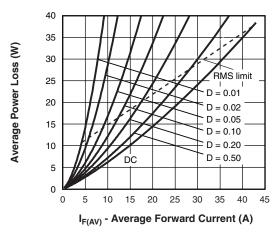


Fig. 6 - Forward Power Loss Characteristics

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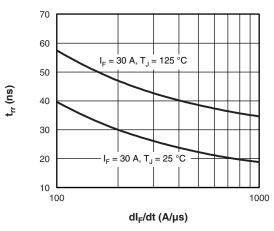


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

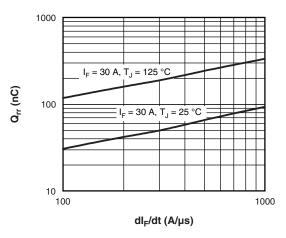


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times R_{\text{thJC}}; \\ \text{Pd} = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ \text{Pd}_{\text{REV}} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$

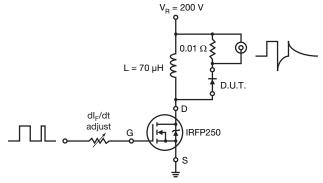
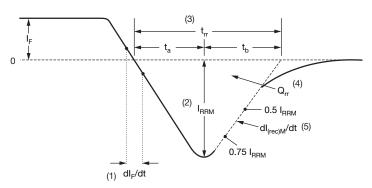


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dl_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

Revision: 10-Jul-15 4 Document Number: 94657

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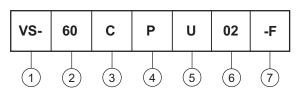




VS-60CPU02-F, VS-60CPU02-N3 Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (60 = 60 A)

3 - Circuit configuration:

C = common cathode

- Package:

P = TO-247AC (modified)

5 - U = ultrafast rectifier

6 - Voltage rating (02 = 200 V)

7 - Environmental digit:

-F = RoHS-compliant and totally lead (Pb)-free

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-60CPU02-F	25	500	Antistatic plastic tube			
VS-60CPU02-N3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95542</u>					
Part marking information	www.vishay.com/doc?95007				

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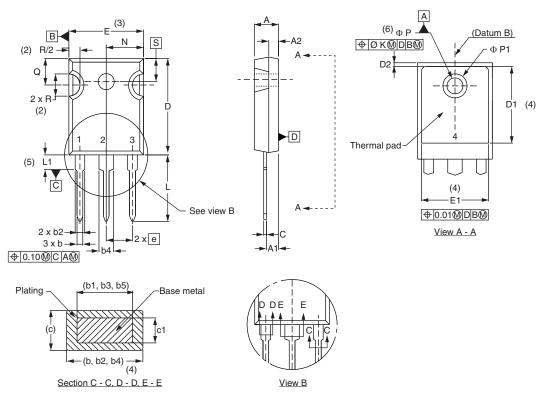


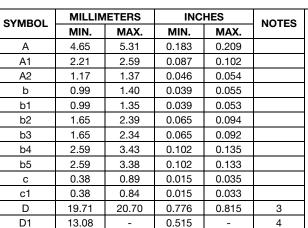
Outline Dimensions

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TO-247 - 50 mils L/F

DIMENSIONS in millimeters and inches





SYMBOL	MILLIMETERS		INCHES		NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.35	0.020	0.053	
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	•	
е	5.46	BSC	0.215	BSC	
ØK	Ø K 0.254		0.0	0.010	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62	BSC	0.3		
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	7.39	-	0.291	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC 0.217 BSC		BSC		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q

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